B 14216.3 ID



Declaration, Power Of Attorney and Petition

Page 1 of 3

WE (I) the undersigned inventor(s), hereby declare(s) that:

My residence, post office address and citizenship are as stated below next to my name,

We (I) believe that we are (I am) the original, first, and joint (sole) inventor(s) of the subject matter which is claimed and for which a patent is sought on the invention entitled A METHOD FOR FORMING, BY

••••	•
CVD, N	NANOSTRUCTURES OF SEMI-CONDUCTOR MATERIAL OF HOMOGENEOUS AND
	CONTROLLED SIZE ON DIELECTRIC MATERIAL
he specification	on of which
	is attached hereto.
	was filed on November 19, 2003
	as Application Serial No. 10/718,109
	and amended on
	was filed as PCT international application
	Number
	on
	and was amended under PCT Article 19
	on
We (I) here the claims, as a	eby state that we (I) have reviewed and understand the contents of the above-identified specification, including amended by any amendment referred to above.
We (I) acki in Section 1.56	nowledge the duty to disclose information known to be material to the patentability of this application as defined for Title 37 Code of Federal Regulations.
patent or inver	by claim foreign priority benefits under 35 U.S.C. § 119 (a)-(d) or § 365 (b) of any foreign application(s) for notificate, or § 365 (a) of any PCT International application which designated at least one country other distances, listed below and have also identified below, by checking the box, any foreign application for patent of the priority international application having a filing date before that of the application on which priority is

for ther t or y is claimed. Prior Foreign Application (s)

Application No.	Country	Day/month/Year	Priority Claimed	
02 14658	FRANCE	22.11.2002	⊠ YES □ NO □ YES □ NO	
			YES NO	
			_ ^~5110	

We (I) hereby claim the benefit under Title 35, United Sapplication(s) listed below.	tates Code, § 119 (e) of any U	Juited States provisional
(Application Number)	(Filing	(Date)
(Application Number)	` -	; Date)
We (I) hereby claim the benefit under 35 U.S.C. §1 International application designating the United States, list this application is not disclosed in the prior United States paragraph of 35 U.S.C. § 112, I acknowledge the duty to d CFR § 1.56 which became available between the filing d date of this application.	or PCT International applica	tion in the manner provided by the first material to patentability as defined in 37 the national or PCT International filing
Application Serial No.	Filing Date	Status (pending, patented, abandoned)
And we (I) hereby appoint: Robert E. Krebs, Registra S. Hanish, Registration No. 42,626; John P. Schaub, R 43,186; Adrienne Yeung, Registration No. 44,000; Stever No. 49,097; William Samuel Niece, Registration No.: P (my) attorneys of record with full power of substitution business in the United States Patent and Trademark (correspondence regarding this application be sent to the Address is: P.O. Box 640640, San Jose, CA 95164-0640. We (I) declare that all statements made herein of on information and belief are believed to be true; and further false statements and the like so made are punishable by funited States Code and that such wilful false statements thereon.	n J. Robbins, Registration No 247,824; and John Klaas Uill on and revocation, to prosect Office connected therewith; the firm of THELEN REID our (my) own knowledge are er that these statements were	40,299; Thierry K. Lo, Registration kema, Registration No. 20,282; our ute this application and transact all and we (I) hereby request that all & PRIEST LLP whose Post Office true and that all statements made on made with the knowledge that willful ander Section 1001 of Title 18 of the
MAZEN Frédéric NAME OF FIRST SOLE INVENTOR Signature of Inventor January 9, 2004	Residence:	FRANCE ress: The same as residence

BARON Thierry	Residence: 11 A Place but Hakuha		
NAME OF SECOND INVENTOR	39000 CREWOSLE FRANCE		
T.B.S.	Citizen of: FLANCE		
Signature of Inventor	Post Office Address: The same as residence		
January 9, 2004 Date			
HARTMANN Jean-Michel	Residence: 510 Rue des Agrunards		
NAME OF THIRD INVENTOR	38240 MEYLAN FRANCE		
248	Citizen of: FRANCE		
Signature of Inventor	Post Office Address: The same as residence		
January 9, 2004 Date	· ·		
SEMERIA Marie-Noëlle	Residence: 1 rue Nolvère		
NAME OF FOURTH INVENTOR	Residence: 1 rue Nolvère 38 000 Grenoble		
	FRANCE		
	Citizen of: France		
Signature of Inventor January 9, 2004 Date	Post Office Address: The same as residence		
	Residence:		
NAME OF FIFTH INVENTOR			
	Citizen of:		
Signature of Inventor	Post Office Address: The same as residence		
Date .			